

ANTREX Electronics

Electronic Components Sourcing Information

Product Reference Information

Part Number:	ZVP4424GTC
Manufacturer:	Diodes Incorporated
Package:	Please confirm with sales
Availability:	Please confirm with sales

Product Page:

<https://antrexco.com/product/details/diodes-incorporated/zvp4424gtc.html>

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New & Original Components

Supplier verification and packaging condition review

CoC / RoHS / REACH documents available on request

Secure sourcing support for OEM / EMS projects

Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

SOT223 P-CHANNEL ENHANCEMENT MODE VERTICAL DMOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} MAX	I _D T _A = +25°C
-240V	9Ω @ V _{GS} = -10V	-480mA

Description and Applications

- Electronic Hook Switches
- Telecoms and Battery Powered Equipment

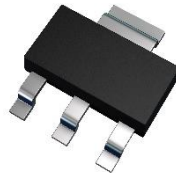
Features and Benefits

- 240 Volt V_{DS}
- R_{DS(ON)} = 8.8Ω Typical at V_{GS} = -3.5V
- Low Threshold and Fast Switching
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)**
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>

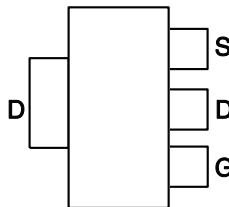
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.112 grams (Approximate)

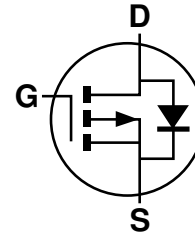
SOT223 (Type DN)



Top View



Pin Out - Top



Equivalent Circuit

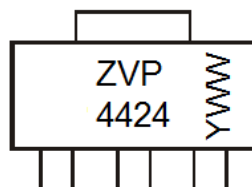
Ordering Information (Note 4)

Part Number	Package	Packing	
		Qty.	Carrier
ZVP4424GTA	SOT223 (Type DN)	1,000	Tape & Reel

- Notes:
- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

SOT223 (Type DN)



ZVP4424 = Product Type Marking Code
YWW = Date Code Marking
Y = Last Digit of Year (ex: 1 = 2021)
WW = Week Code (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	-240	V
Gate-Source Voltage	V _{GSS}	±40	V
Continuous Drain Current (@ T _A = +25°C) (Note 5)	I _D	-480	mA
Maximum Body Diode Forward Current (@ T _A = +25°C) (Note 5)	I _S	-480	mA
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)	I _{DM}	-1.5	A
Pulsed Source Current (10μs Pulse, Duty Cycle = 1%)	I _{SM}	-1.5	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

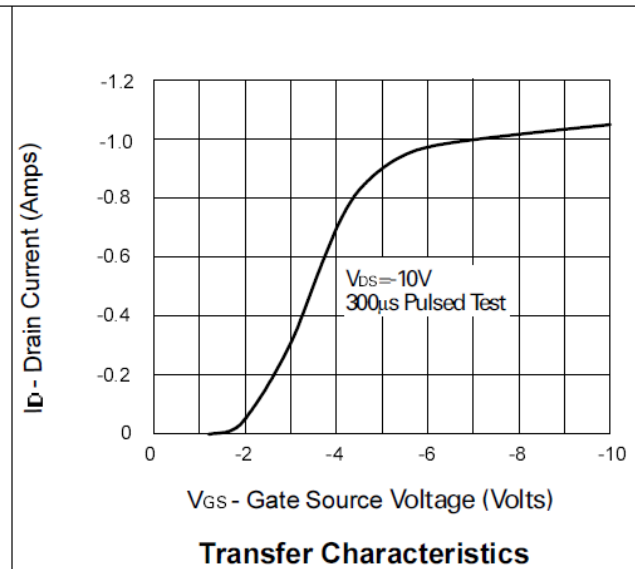
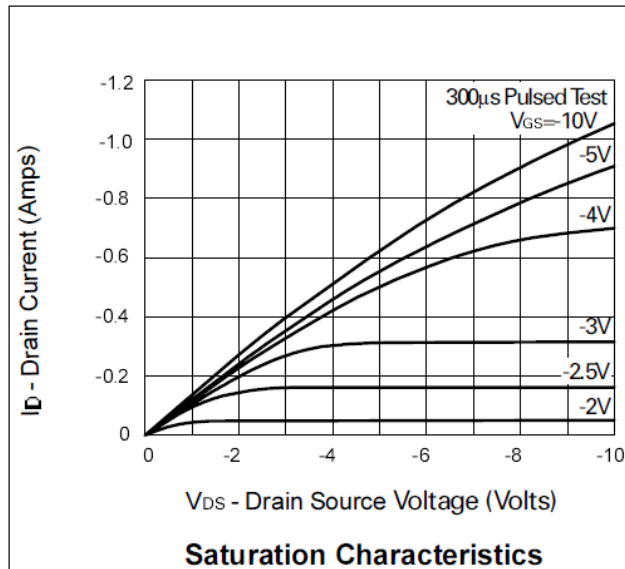
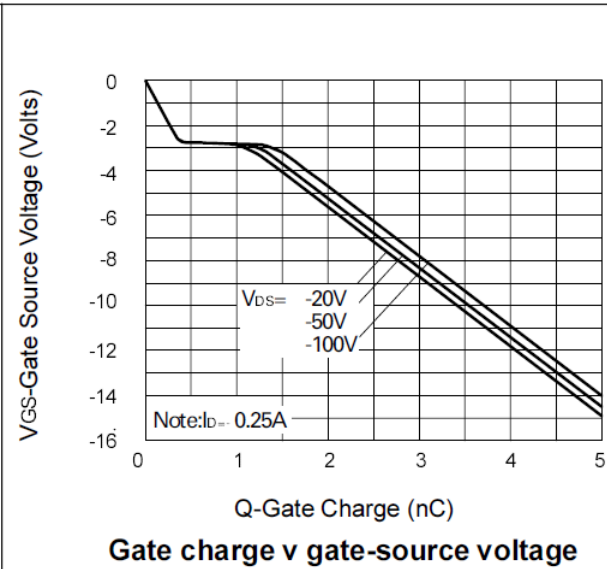
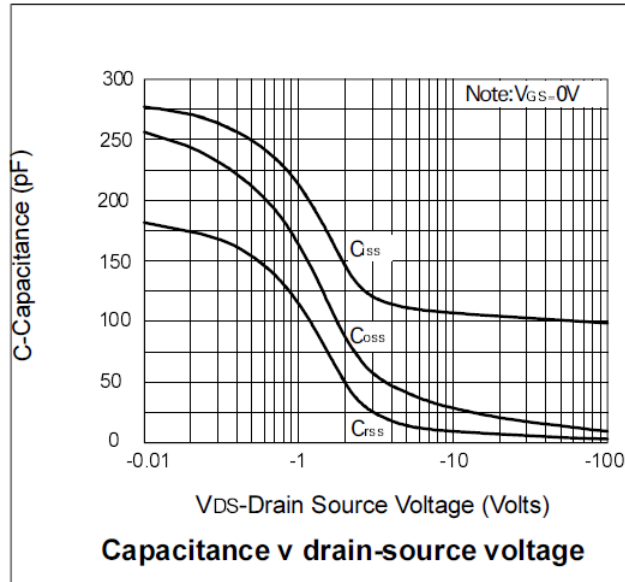
Characteristic	Symbol	Value	Unit
Power Dissipation (@ T _A = +25°C) (Note 5)	P _D	2.5	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	R _{θJA}	50	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise stated.)

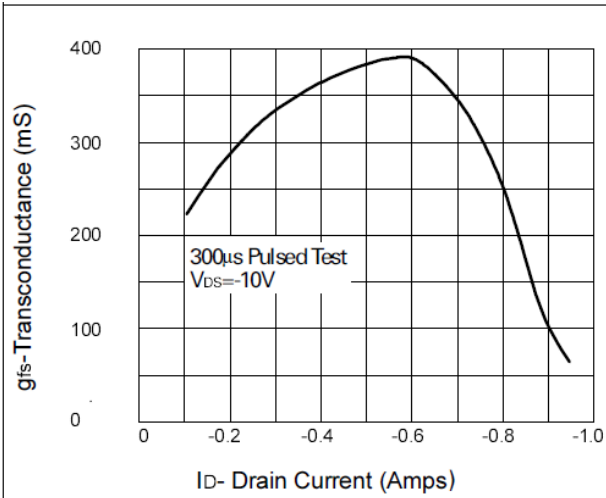
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV _{DSS}	-240	—	—	V	V _{GS} = 0V, I _D = -1mA
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	—	—	-10 -100	μA μA	V _{DS} = -240V, V _{GS} = 0V V _{DS} = -190V, V _{GS} = 0V T _A = +125°C
Gate-Source Leakage	I _{GSS}	—	—	100	nA	V _{GS} = ±40V, V _{DS} = 0V
On-State Drain Current	I _{D(ON)}	-0.75	-1.0	—	A	V _{GS} = -10V, V _{DS} = -10V
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(TH)}	-0.7	-1.4	-2.0	V	V _{DS} = V _{GS} , I _D = -1mA
Static Drain-Source On-Resistance	R _{DS(ON)}	—	7.1 8.8	9 11	Ω Ω	V _{GS} = -10V, I _D = -200mA V _{GS} = -3.5V, I _D = -100mA
Forward Transconductance (Notes 7 & 8)	g _{FS}	125	—	—	mS	V _{DS} = -10V, I _D = -0.2A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C _{iss}	—	100	200	pF	V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{oss}	—	18	25	pF	
Reverse Transfer Capacitance	C _{rss}	—	5	15	pF	
Turn-On Delay Time (Note 9)	t _{D(ON)}	—	8	15	ns	V _{DD} ≈ -50V, I _D = -0.25A, V _{GEN} = -10V
Turn-On Rise Time (Note 9)	t _r	—	8	15	ns	
Turn-Off Delay Time (Note 9)	t _{D(OFF)}	—	26	40	ns	
Turn-Off Fall Time (Note 9)	t _f	—	20	30	ns	

- Notes:
- Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square pad layout.
 - Short duration pulse test used to minimize self-heating effect.
 - Measured under pulsed conditions. Pulse width = 300ms. Duty cycle ≤ 2%.
 - Guaranteed by design. Not subject to production testing.
 - Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator
spice parameter data is available upon request for this device.

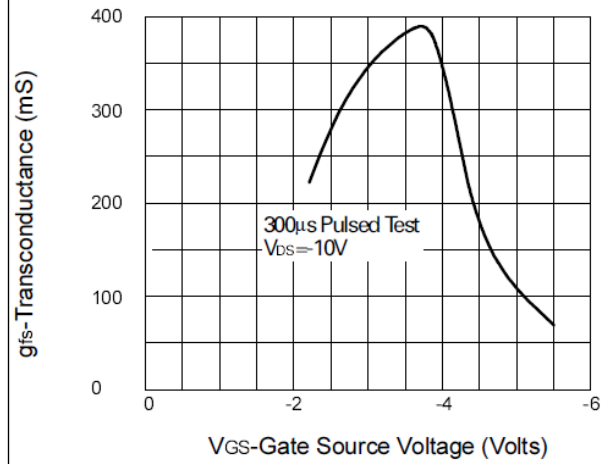
Typical Characteristics



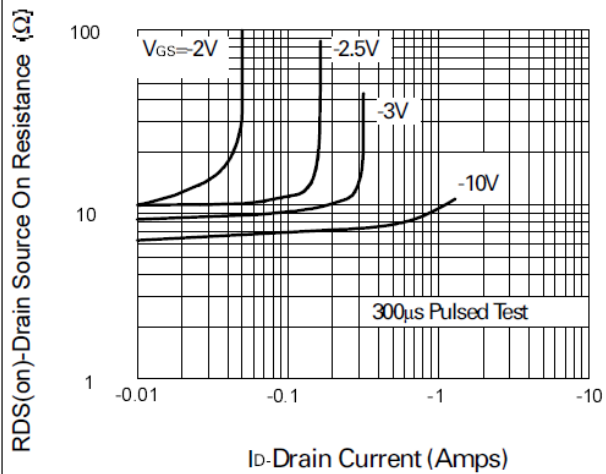
Typical Characteristics (continued)



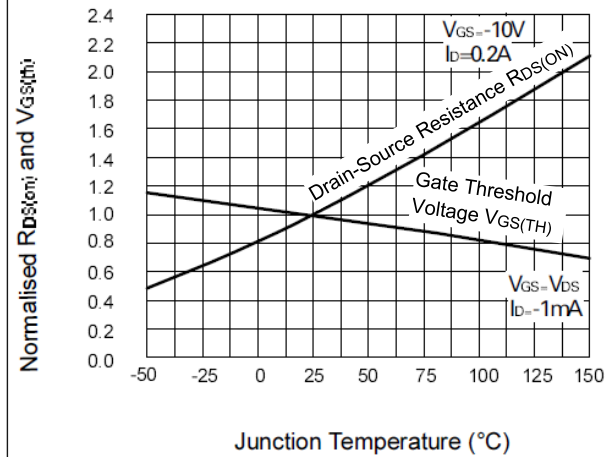
Transconductance v drain current



Transconductance v gate-source voltage



On-resistance vs Drain Current



Normalised $R_{DS(on)}$ and $V_{GS(th)}$ vs Temperature

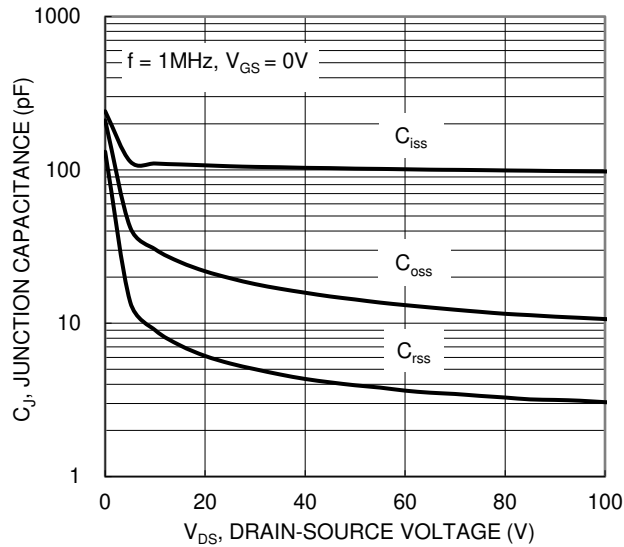


Figure 1. Junction Capacitance vs. Drain-Source Voltage

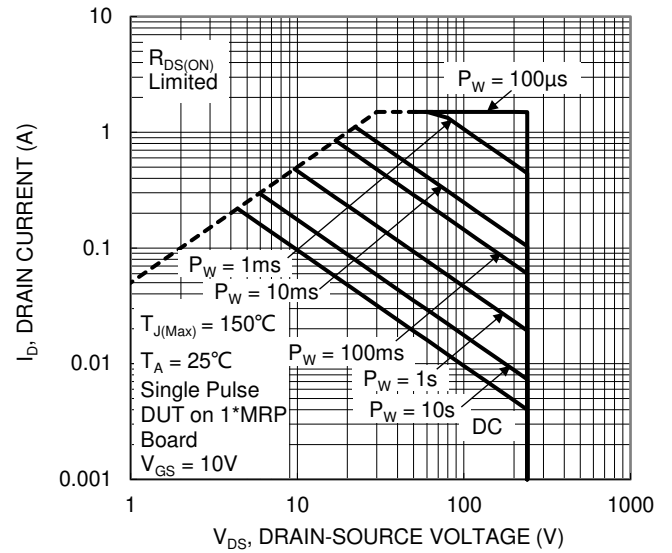


Figure 2. SOA, Safe Operation Area

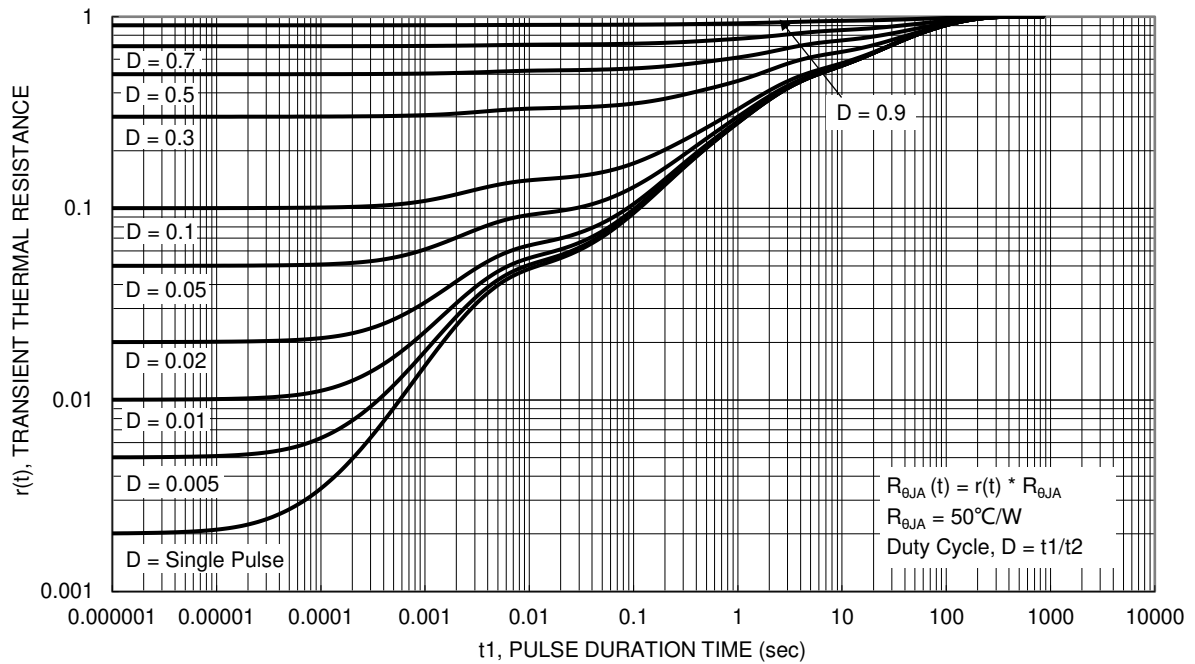
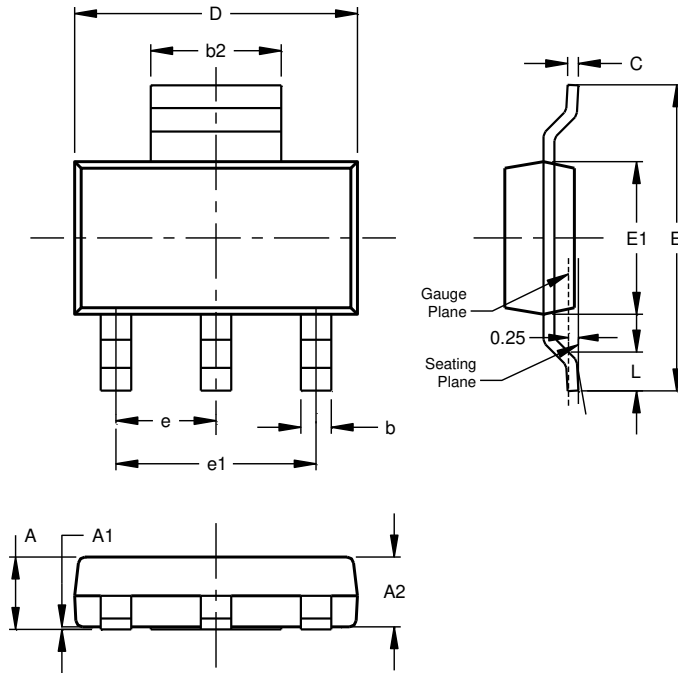


Figure 3. Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)

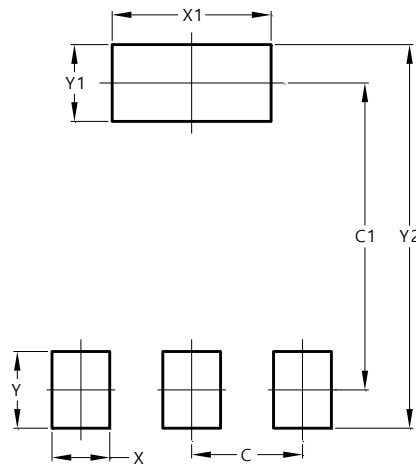


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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